



Welcome to **E-XFL.COM**

Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

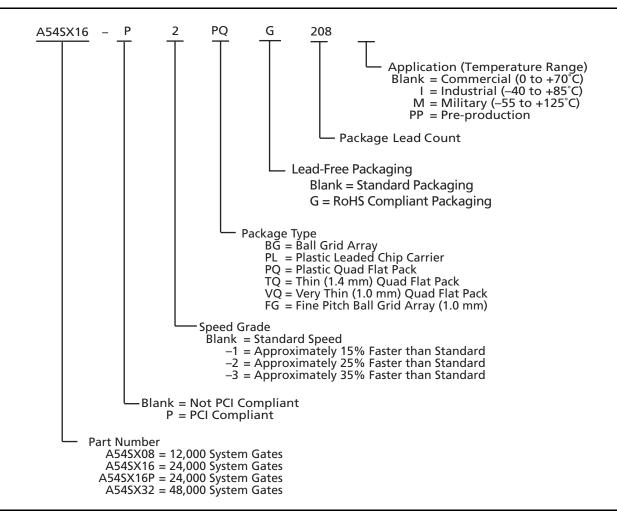
The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	1452
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	147
Number of Gates	24000
Voltage - Supply	3V ~ 3.6V, 4.75V ~ 5.25V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	176-LQFP
Supplier Device Package	176-TQFP (24x24)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a54sx16-1tq176i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Ordering Information



Plastic Device Resources

	User I/Os (including clock buffers)							
Device	PLCC 84-Pin	VQFP 100-Pin	PQFP 208-Pin	TQFP 144-Pin	TQFP 176-Pin	PBGA 313-Pin	PBGA 329-Pin	FBGA 144-Pin
A54SX08	69	81	130	113	128	_	_	111
A54SX16	_	81	175	-	147	_	_	_
A54SX16P	_	81	175	113	147	_	_	_
A54SX32	_	-	174	113	147	249	249	_

Note: Package Definitions (Consult your local Actel sales representative for product availability):

PLCC = Plastic Leaded Chip Carrier

PQFP = Plastic Quad Flat Pack

TQFP = Thin Quad Flat Pack

VQFP = Very Thin Quad Flat Pack

PBGA = Plastic Ball Grid Array

FBGA = Fine Pitch (1.0 mm) Ball Grid Array

ii v3.2

Table of Contents

SX Family FPGAs
General Description 1-
SX Family Architecture
Programming
3.3 V / 5 V Operating Conditions 1-
PCI Compliance for the SX Family1-
A54SX16P AC Specifications for (PCI Operation)
A54SX16P DC Specifications (3.3 V PCI Operation)
A54SX16P AC Specifications (3.3 V PCI Operation)
Power-Up Sequencing 1-1
Power-Down Sequencing
Evaluating Power in SX Devices
SX Timing Model 1-2
Timing Characteristics 1-23
Package Pin Assignments
84-Pin PLCC
208-Pin PQFP
144-Pin TQFP
176-Pin TQFP
100-Pin VQFP
313-Pin PBGA
329-Pin PBGA
144-Pin FBGA
Datasheet Information
List of Changes
Datasheet Categories
International Traffic in Arms Regulations (ITAR) and Export Administration Regulations (EAR)
NEULIALIUIIS (EAN)



General Description

The Actel SX family of FPGAs features a sea-of-modules architecture that delivers device performance and integration levels not currently achieved by any other FPGA architecture. SX devices greatly simplify design time, enable dramatic reductions in design costs and power consumption, and further decrease time to market for performance-intensive applications.

The Actel SX architecture features two types of logic modules, the combinatorial cell (C-cell) and the register cell (R-cell), each optimized for fast and efficient mapping of synthesized logic functions. The routing and interconnect resources are in the metal layers above the logic modules, providing optimal use of silicon. This enables the entire floor of the device to be spanned with an uninterrupted grid of fine-grained, synthesis-friendly logic modules (or "sea-of-modules"), which reduces the distance signals have to travel between logic modules. To minimize signal propagation delay, SX devices employ both local and general routing resources. The high-speed local routing resources (DirectConnect and FastConnect) enable very fast local signal propagation that is optimal for fast counters, state machines, and datapath logic. The general system of segmented routing tracks allows any logic module in the array to be connected to any other logic or I/O module. Within this system, propagation delay is minimized by limiting the number of antifuse interconnect elements to five (90 percent of connections typically use only three antifuses). The unique local and general routing structure featured in SX devices gives fast and predictable performance, allows 100 percent pin-locking with full logic utilization, enables concurrent PCB development, reduces design time, and allows designers to achieve performance goals with minimum effort.

Further complementing SX's flexible routing structure is a hardwired, constantly loaded clock network that has been tuned to provide fast clock propagation with minimal clock skew. Additionally, the high performance of the internal logic has eliminated the need to embed latches or flip-flops in the I/O cells to achieve fast clock-to-out or fast input setup times. SX devices have easy to use I/O cells that do not require HDL instantiation, facilitating design reuse and reducing design and verification time.

SX Family Architecture

The SX family architecture was designed to satisfy nextgeneration performance and integration requirements for production-volume designs in a broad range of applications.

Programmable Interconnect Element

The SX family provides efficient use of silicon by locating the routing interconnect resources between the Metal 2 (M2) and Metal 3 (M3) layers (Figure 1-1 on page 1-2). This completely eliminates the channels of routing and interconnect resources between logic modules (as implemented on SRAM FPGAs and previous generations of antifuse FPGAs), and enables the entire floor of the device to be spanned with an uninterrupted grid of logic modules.

Interconnection between these logic modules is achieved using The Actel patented metal-to-metal programmable antifuse interconnect elements, which are embedded between the M2 and M3 layers. The antifuses are normally open circuit and, when programmed, form a permanent low-impedance connection.

The extremely small size of these interconnect elements gives the SX family abundant routing resources and provides excellent protection against design pirating. Reverse engineering is virtually impossible because it is extremely difficult to distinguish between programmed and unprogrammed antifuses, and there is no configuration bitstream to intercept.

Additionally, the interconnect elements (i.e., the antifuses and metal tracks) have lower capacitance and lower resistance than any other device of similar capacity, leading to the fastest signal propagation in the industry.

Logic Module Design

The SX family architecture is described as a "sea-of-modules" architecture because the entire floor of the device is covered with a grid of logic modules with virtually no chip area lost to interconnect elements or routing. The Actel SX family provides two types of logic modules, the register cell (R-cell) and the combinatorial cell (C-cell).

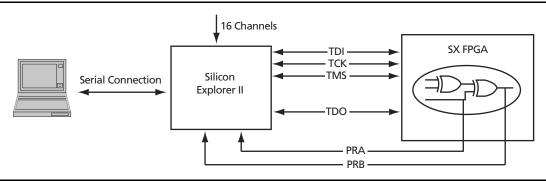


Figure 1-8 • Probe Setup

Programming

Device programming is supported through Silicon Sculptor series of programmers. In particular, Silicon Sculptor II are compact, robust, single-site and multi-site device programmer for the PC.

With standalone software, Silicon Sculptor II allows concurrent programming of multiple units from the same PC, ensuring the fastest programming times possible. Each fuse is subsequently verified by Silicon Sculptor II to insure correct programming. In addition, integrity tests ensure that no extra fuses are programmed. Silicon Sculptor II also provides extensive hardware self-testing capability.

The procedure for programming an SX device using Silicon Sculptor II are as follows:

- 1. Load the .AFM file
- 2. Select the device to be programmed
- 3. Begin programming

When the design is ready to go to production, Actel offers device volume-programming services either through distribution partners or via in-house programming from the factory.

For more details on programming SX devices, refer to the *Programming Antifuse Devices* application note and the *Silicon Sculptor II User's Guide*.

3.3 V / 5 V Operating Conditions

Table 1-3 • Absolute Maximum Ratings¹

Symbol	Parameter	Limits	Units
V_{CCR}^2	DC Supply Voltage ³	-0.3 to + 6.0	V
V_{CCA}^2	DC Supply Voltage	-0.3 to + 4.0	V
V _{CCI} ²	DC Supply Voltage (A54SX08, A54SX16, A54SX32)	-0.3 to + 4.0	V
V _{CCI} ²	DC Supply Voltage (A54SX16P)	-0.3 to + 6.0	V
V _I	Input Voltage	-0.5 to + 5.5	V
V _O	Output Voltage	-0.5 to + 3.6	V
I _{IO}	I/O Source Sink Current ³	−30 to + 5.0	mA
T _{STG}	Storage Temperature	–65 to +150	°C

Notes

- 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Device should not be operated outside the Recommended Operating Conditions.
- 2. V_{CCR} in the A54SX16P must be greater than or equal to V_{CCI} during power-up and power-down sequences and during normal operation.
- 3. Device inputs are normally high impedance and draw extremely low current. However, when input voltage is greater than V_{CC} + 0.5 V or less than GND 0.5 V, the internal protection diodes will forward-bias and can draw excessive current.



EQ 1-2

Figure 1-9 shows the 5.0 V PCI V/I curve and the minimum and maximum PCI drive characteristics of the A54SX16P device.

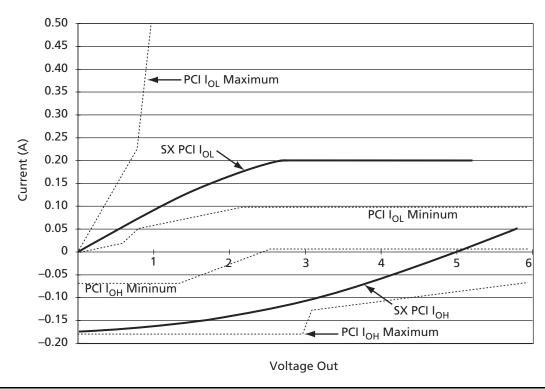


Figure 1-9 • 5.0 V PCI Curve for A54SX16P Device

$$I_{OH} = 11.9 \times (V_{OUT} - 5.25) \times (V_{OUT} + 2.45)$$

$$I_{OL} = 78.5 \times V_{OUT} \times (4.4 - V_{OUT})$$
for $V_{CC} > V_{OUT} > 3.1 \text{ V}$

$$EQ 1-1$$

A54SX16P DC Specifications (3.3 V PCI Operation)

Table 1-8 • A54SX16P DC Specifications (3.3 V PCI Operation)

Symbol	Parameter	Condition	Min.	Max.	Units
V_{CCA}	Supply Voltage for Array		3.0	3.6	V
V_{CCR}	Supply Voltage required for Internal Biasing		3.0	3.6	V
V_{CCI}	Supply Voltage for I/Os		3.0	3.6	V
V_{IH}	Input High Voltage		0.5V _{CC}	$V_{CC} + 0.5$	V
V_{IL}	Input Low Voltage		-0.5	0.3V _{CC}	V
I _{IPU}	Input Pull-up Voltage ¹		0.7V _{CC}		V
I _{IL}	Input Leakage Current ²	$0 < V_{IN} < V_{CC}$		±10	μΑ
V_{OH}	Output High Voltage	I _{OUT} = -500 μA	0.9V _{CC}		V
V_{OL}	Output Low Voltage	I _{OUT} = 1500 μA		0.1V _{CC}	V
C _{IN}	Input Pin Capacitance ³			10	pF
C _{CLK}	CLK Pin Capacitance		5	12	pF
C _{IDSEL}	IDSEL Pin Capacitance ⁴			8	pF

Notes:

- 1. This specification should be guaranteed by design. It is the minimum voltage to which pull-up resistors are calculated to pull a floated network. Applications sensitive to static power utilization should assure that the input buffer is conducting minimum current at this input voltage.
- 2. Input leakage currents include hi-Z output leakage for all bidirectional buffers with tristate outputs.
- 3. Absolute maximum pin capacitance for a PCI input is 10 pF (except for CLK).
- 4. Lower capacitance on this input-only pin allows for non-resistive coupling to AD[xx].

1-12 v3.2

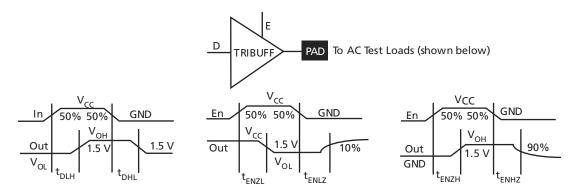


Figure 1-13 • Output Buffer Delays

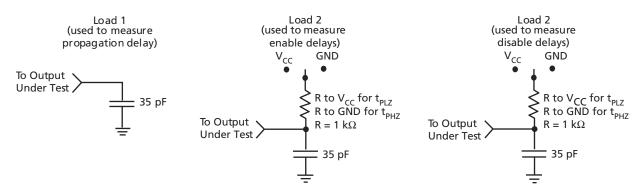


Figure 1-14 • AC Test Loads



Figure 1-15 • Input Buffer Delays

Figure 1-16 • C-Cell Delays

1-22 v3.2

Register Cell Timing Characteristics

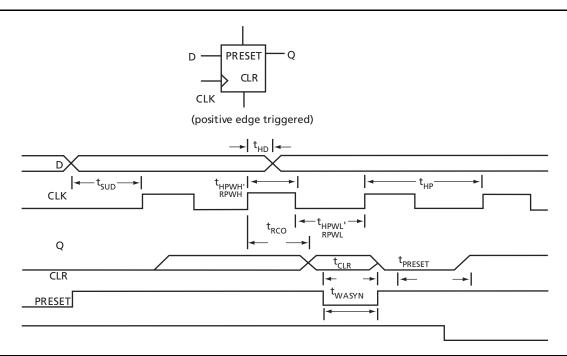


Figure 1-17 • Flip-Flops

Timing Characteristics

Timing characteristics for SX devices fall into three categories: family-dependent, device-dependent, and design-dependent. The input and output buffer characteristics are common to all SX family members. Internal routing delays are device-dependent. Design dependency means actual delays are not determined until after placement and routing of the user's design is complete. Delay values may then be determined by using the DirectTime Analyzer utility or performing simulation with post-layout delays.

Critical Nets and Typical Nets

Propagation delays are expressed only for typical nets, which are used for initial design performance evaluation. Critical net delays can then be applied to the most time-critical paths. Critical nets are determined by net property assignment prior to placement and routing. Up to 6% of the nets in a design may be designated as critical, while 90% of the nets in a design are typical.

Long Tracks

Some nets in the design use long tracks. Long tracks are special routing resources that span multiple rows, columns, or modules. Long tracks employ three and sometimes five antifuse connections. This increases capacitance and resistance, resulting in longer net delays for macros connected to long tracks. Typically up to 6 percent of nets in a fully utilized device require long tracks. Long tracks contribute approximately 4 ns to 8.4 ns delay. This additional delay is represented statistically in higher fanout (FO = 24) routing delays in the datasheet specifications section.

Timing Derating

SX devices are manufactured in a CMOS process. Therefore, device performance varies according to temperature, voltage, and process variations. Minimum timing parameters reflect maximum operating voltage, minimum operating temperature, and best-case processing. Maximum timing parameters reflect minimum operating voltage, maximum operating temperature, and worst-case processing.

A54SX16P Timing Characteristics

Table 1-19 • A54SX16P Timing Characteristics (Worst-Case Commercial Conditions, V_{CCR} = 4.75 V, V_{CCA},V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' \$	Speed	'-2' \$	Speed	'-1' \$	Speed	'Std'	Speed	
Parameter	Description	Min.	Мах.	Min.	Max.	Min.	Max.	Min.	Мах.	Units
C-Cell Propagation Delays ¹										
t _{PD}	Internal Array Module		0.6		0.7		8.0		0.9	ns
Predicted R	outing Delays ²									
t _{DC}	FO = 1 Routing Delay, Direct Connect		0.1		0.1		0.1		0.1	ns
t _{FC}	FO = 1 Routing Delay, Fast Connect		0.3		0.4		0.4		0.5	ns
t _{RD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{RD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{RD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{RD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{RD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{RD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns
R-Cell Timir	ng									
t _{RCO}	Sequential Clock-to-Q		0.9		1.1		1.3		1.4	ns
t _{CLR}	Asynchronous Clear-to-Q		0.5		0.6		0.7		0.8	ns
t _{PRESET}	Asynchronous Preset-to-Q		0.7		8.0		0.9		1.0	ns
t _{SUD}	Flip-Flop Data Input Set-Up	0.5		0.5		0.7		0.8		ns
t _{HD}	Flip-Flop Data Input Hold	0.0		0.0		0.0		0.0		ns
t _{WASYN}	Asynchronous Pulse Width	1.4		1.6		1.8		2.1		ns
Input Modu	ıle Propagation Delays									
t _{INYH}	Input Data Pad-to-Y HIGH		1.5		1.7		1.9		2.2	ns
t _{INYL}	Input Data Pad-to-Y LOW		1.5		1.7		1.9		2.2	ns
Predicted In	nput Routing Delays ²									
t _{IRD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{IRD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{IRD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{IRD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{IRD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{IRD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns

Note:

- 1. For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn} , t_{RCO} + t_{RD1} + t_{PDn} , or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

3. Delays based on 10 pF loading.

1-28 v3.2



A54SX32 Timing Characteristics

Table 1-20 • A54SX32 Timing Characteristics (Worst-Case Commercial Conditions, V_{CCR}= 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' \$	Speed	'-2' 9	Speed	'-1' 9	Speed	'Std'	Speed	
Parameter	Description	Min.	Мах.	Min.	Мах.	Min.	Мах.	Min.	Мах.	Units
C-Cell Propa	agation Delays ¹									
t _{PD}	Internal Array Module		0.6		0.7		8.0		0.9	ns
Predicted R	outing Delays ²									
t _{DC}	FO = 1 Routing Delay, Direct Connect		0.1		0.1		0.1		0.1	ns
t _{FC}	FO = 1 Routing Delay, Fast Connect		0.3		0.4		0.4		0.5	ns
t _{RD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{RD2}	FO = 2 Routing Delay		0.7		8.0		0.9		1.0	ns
t _{RD3}	FO = 3 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{RD4}	FO = 4 Routing Delay		1.4		1.6		1.8		2.1	ns
t _{RD8}	FO = 8 Routing Delay		2.7		3.1		3.5		4.1	ns
t _{RD12}	FO = 12 Routing Delay		4.0		4.7		5.3		6.2	ns
R-Cell Timir	ng									
t _{RCO}	Sequential Clock-to-Q		0.8		1.1		1.3		1.4	ns
t _{CLR}	Asynchronous Clear-to-Q		0.5		0.6		0.7		8.0	ns
t _{PRESET}	Asynchronous Preset-to-Q		0.7		8.0		0.9		1.0	ns
t _{SUD}	Flip-Flop Data Input Set-Up	0.5		0.6		0.7		0.8		ns
t _{HD}	Flip-Flop Data Input Hold	0.0		0.0		0.0		0.0		ns
t _{WASYN}	Asynchronous Pulse Width	1.4		1.6		1.8		2.1		ns
Input Modu	ıle Propagation Delays									
t _{INYH}	Input Data Pad-to-Y HIGH		1.5		1.7		1.9		2.2	ns
t _{INYL}	Input Data Pad-to-Y LOW		1.5		1.7		1.9		2.2	ns
Predicted In	nput Routing Delays ²									
t _{IRD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{IRD2}	FO = 2 Routing Delay		0.7		8.0		0.9		1.0	ns
t _{IRD3}	FO = 3 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{IRD4}	FO = 4 Routing Delay		1.4		1.6		1.8		2.1	ns
t _{IRD8}	FO = 8 Routing Delay		2.7		3.1		3.5		4.1	ns
t _{IRD12}	FO = 12 Routing Delay		4.0		4.7		5.3		6.2	ns

Note:

- 1. For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn_r} t_{RCO} + t_{RD1} + t_{PDn_r} or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.
- 3. Delays based on 35 pF loading, except t_{ENZL} and t_{ENZH} . For t_{ENZL} and t_{ENZH} the loading is 5 pF.



Pin Description

CLKA/B Clock A and B

These pins are 3.3 V / 5.0 V PCI/TTL clock inputs for clock distribution networks. The clock input is buffered prior to clocking the R-cells. If not used, this pin must be set LOW or HIGH on the board. It must not be left floating. (For A54SX72A, these clocks can be configured as bidirectional.)

GND Ground

LOW supply voltage.

HCLK Dedicated (hardwired) Array Clock

This pin is the 3.3 V / 5.0 V PCI/TTL clock input for sequential modules. This input is directly wired to each R-cell and offers clock speeds independent of the number of R-cells being driven. If not used, this pin must be set LOW or HIGH on the board. It must not be left floating.

I/O Input/Output

The I/O pin functions as an input, output, tristate, or bidirectional buffer. Based on certain configurations, input and output levels are compatible with standard TTL, LVTTL, 3.3 V PCI or 5.0 V PCI specifications. Unused I/O pins are automatically tristated by the Designer Series software.

NC No Connection

This pin is not connected to circuitry within the device.

PRA, I/O Probe A

The Probe A pin is used to output data from any userdefined design node within the device. This independent diagnostic pin can be used in conjunction with the Probe B pin to allow real-time diagnostic output of any signal path within the device. The Probe A pin can be used as a user-defined I/O when verification has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality.

PRB. I/O Probe B

The Probe B pin is used to output data from any node within the device. This diagnostic pin can be used in conjunction with the Probe A pin to allow real-time diagnostic output of any signal path within the device. The Probe B pin can be used as a user-defined I/O when verification has been completed. The pin's probe capabilities can be permanently disabled to protect programmed design confidentiality.

TCK Test Clock

Test clock input for diagnostic probe and device programming. In flexible mode, TCK becomes active when the TMS pin is set LOW (refer to Table 1-2 on page 1-6). This pin functions as an I/O when the boundary scan state machine reaches the "logic reset" state.

TDI Test Data Input

Serial input for boundary scan testing and diagnostic probe. In flexible mode, TDI is active when the TMS pin is set LOW (refer to Table 1-2 on page 1-6). This pin functions as an I/O when the boundary scan state machine reaches the "logic reset" state.

TDO Test Data Output

Serial output for boundary scan testing. In flexible mode, TDO is active when the TMS pin is set LOW (refer to Table 1-2 on page 1-6). This pin functions as an I/O when the boundary scan state machine reaches the "logic reset" state.

TMS Test Mode Select

The TMS pin controls the use of the IEEE 1149.1 Boundary Scan pins (TCK, TDI, TDO). In flexible mode when the TMS pin is set LOW, the TCK, TDI, and TDO pins are boundary scan pins (refer to Table 1-2 on page 1-6). Once the boundary scan pins are in test mode, they will remain in that mode until the internal boundary scan state machine reaches the "logic reset" state. At this point, the boundary scan pins will be released and will function as regular I/O pins. The "logic reset" state is reached 5 TCK cycles after the TMS pin is set HIGH. In dedicated test mode, TMS functions as specified in the IEEE 1149.1 specifications.

V_{CCI} Supply Voltage

Supply voltage for I/Os. See Table 1-1 on page 1-5.

V_{CCA} Supply Voltage

Supply voltage for Array. See Table 1-1 on page 1-5.

V_{CCR} Supply Voltage

Supply voltage for input tolerance (required for internal biasing). See Table 1-1 on page 1-5.

Package Pin Assignments

84-Pin PLCC

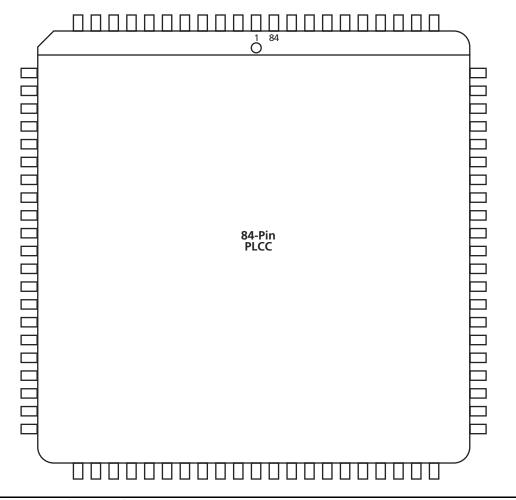


Figure 2-1 • 84-Pin PLCC (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

208-Pin PQFP					
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function		
1	GND	GND	GND		
2	TDI, I/O	TDI, I/O	TDI, I/O		
3	I/O	1/0	I/O		
4	NC	1/0	I/O		
5	I/O	1/0	I/O		
6	NC	1/0	I/O		
7	I/O	1/0	I/O		
8	I/O	1/0	I/O		
9	I/O	1/0	I/O		
10	I/O	1/0	I/O		
11	TMS	TMS	TMS		
12	V _{CCI}	V _{CCI}	V _{CCI}		
13	I/O	1/0	I/O		
14	NC	1/0	I/O		
15	I/O	I/O	I/O		
16	I/O	I/O	I/O		
17	NC	1/0	I/O		
18	I/O	1/0	I/O		
19	I/O	1/0	I/O		
20	NC	1/0	I/O		
21	I/O	I/O	I/O		
22	I/O	I/O	I/O		
23	NC	I/O	I/O		
24	I/O	I/O	I/O		
25	V_{CCR}	V_{CCR}	V_{CCR}		
26	GND	GND	GND		
27	V_{CCA}	V _{CCA}	V_{CCA}		
28	GND	GND	GND		
29	I/O	1/0	I/O		
30	I/O	1/0	I/O		
31	NC	1/0	I/O		
32	I/O	I/O	I/O		
33	I/O	I/O	I/O		
34	I/O	I/O	I/O		
35	NC	I/O	I/O		
36	I/O	I/O	I/O		

	208-Pin PQFP					
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function			
37	I/O	I/O	I/O			
38	I/O	I/O	I/O			
39	NC	I/O	I/O			
40	V _{CCI}	V _{CCI}	V _{CCI}			
41	V_{CCA}	V_{CCA}	V_{CCA}			
42	I/O	I/O	I/O			
43	I/O	I/O	I/O			
44	I/O	I/O	I/O			
45	I/O	I/O	I/O			
46	I/O	I/O	I/O			
47	I/O	I/O	I/O			
48	NC	I/O	I/O			
49	I/O	I/O	I/O			
50	NC	I/O	I/O			
51	I/O	I/O	I/O			
52	GND	GND	GND			
53	I/O	1/0	I/O			
54	I/O	1/0	I/O			
55	I/O	I/O	I/O			
56	I/O	I/O	I/O			
57	I/O	I/O	I/O			
58	I/O	I/O	I/O			
59	I/O	I/O	I/O			
60	V _{CCI}	V _{CCI}	V _{CCI}			
61	NC	I/O	I/O			
62	I/O	I/O	I/O			
63	I/O	I/O	I/O			
64	NC	I/O	I/O			
65*	I/O	I/O	NC*			
66	I/O	I/O	I/O			
67	NC	I/O	I/O			
68	I/O	I/O	I/O			
69	I/O	I/O	I/O			
70	NC	I/O	I/O			
71	I/O	I/O	I/O			
72	I/O	I/O	I/O			

Note: * Note that Pin 65 in the A54SX32—PQ208 is a no connect (NC).

2-4 v3.2

144-Pin TQFP

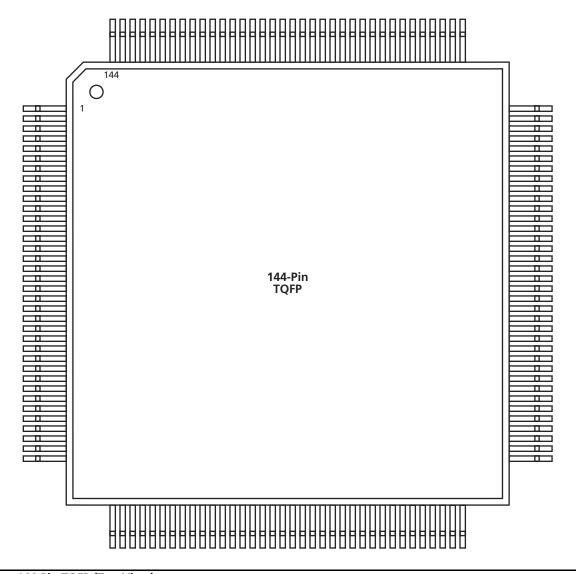


Figure 2-3 • 144-Pin TQFP (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

176-Pin TQFP

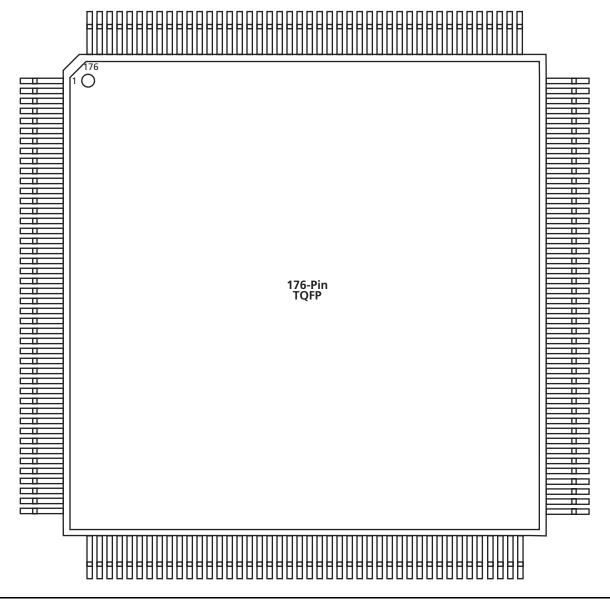


Figure 2-4 • 176-Pin TQFP (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

2-10 v3.2



313-Pin PBGA					
Pin	A54SX32				
Number	Function				
A1	GND				
A3	NC				
A5	1/0				
A7	1/0				
A9	1/0				
A11	I/O				
A13	V_{CCR}				
A15	I/O				
A17	1/0				
A19	1/0				
A21	I/O				
A23	NC				
A25	GND				
AA1	I/O				
AA3	I/O				
AA5	NC				
AA7	I/O				
AA9	NC				
AA11	I/O				
AA13	1/0				
AA15	I/O				
AA17	1/0				
AA19	I/O				
AA21	1/0				
AA23	NC				
AA25	I/O				
AB2	NC				
AB4	NC				
AB6	1/0				
AB8	I/O				
AB10	1/0				
AB12	I/O				
AB14	1/0				
AB16	1/0				
AB18	V _{CCI}				
AB20	NC				
AB22	I/O				
AB24	I/O				
AC1	I/O				
AC3	I/O				

313-Pin PBGA Pin A54SX32		
AC5	I/O	
AC7	1/0	
AC9	I/O	
AC11	I/O	
AC13	V_{CCR}	
AC15	I/O	
AC17	I/O	
AC19	I/O	
AC21	1/0	
AC23	I/O	
AC25	NC	
AD2	GND	
AD4	I/O	
AD6	V _{CCI}	
AD8	1/0	
AD10	1/0	
AD12	PRB, I/O	
AD14	1/0	
AD16	1/0	
AD18	1/0	
AD20	1/0	
AD22	NC	
AD24	1/0	
AE1	NC NC	
AE3	1/0	
AE5	1/0	
AE7	1/0	
AE9	1/0	
AE11	1/0	
AE13	V _{CCA}	
AE15	I/O	
AE17	1/0	
AE19	1/0	
AE21	1/0	
AE23	TDO, I/O	
AE25	GND	
B2	TCK, I/O	
B4	/O	
B6	1/0	
B8	1/0	
DΟ	1/0	

313-Pin PBGA	
Pin	A54SX32
Number	Function
B10	I/O
B12	I/O
B14	I/O
B16	1/0
B18	I/O
B20	I/O
B22	I/O
B24	1/0
C1	TDI, I/O
C3	1/0
C5	NC
C7	1/0
C9	1/0
C11	1/0
C13	V _{CCI}
C15	I/O
C17	I/O
C19	V _{CCI}
C21	I/O
C23	I/O
C25	NC
D2	1/0
D4	NC
D6	1/0
D8	I/O
D10	I/O
D12	I/O
D14	I/O
D16	I/O
D18	I/O
D20	I/O
D22	I/O
D24	NC
E1	I/O
E3	NC
E5	I/O
E7	I/O
E9	I/O
E11	I/O
E13	V_{CCA}

313-Pin PBGA	
Pin	A54SX32
Number	Function
E15	I/O
E17	I/O
E19	I/O
E21	I/O
E23	I/O
E25	I/O
F2	I/O
F4	I/O
F6	NC
F8	I/O
F10	NC
F12	I/O
F14	I/O
F16	NC
F18	I/O
F20	I/O
F22	I/O
F24	I/O
G1	I/O
G3	TMS
G5	I/O
G7	I/O
G9	V _{CCI}
G11	I/O
G13	CLKB
G15	I/O
G17	I/O
G19	I/O
G21	I/O
G23	I/O
G25	I/O
H2	1/0
H4	1/0
H6	1/0
H8	I/O
H10	I/O
H12	PRA, I/O
H14	1/0
H16	I/O
H18	NC
ПО	IVC

329-Pin PBGA

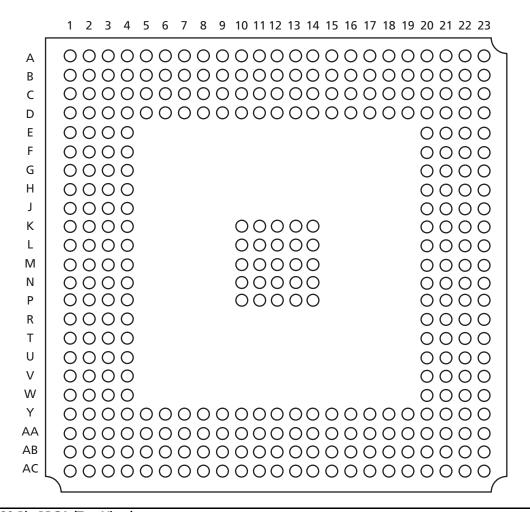


Figure 2-7 • 329-Pin PBGA (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

329-Pin PBGA	
Pin Number	A54SX32 Function
T22	I/O
T23	I/O
U1	I/O
U2	1/0
U3	V_{CCA}
U4	1/0
U20	I/O
U21	V_{CCA}
U22	I/O
U23	I/O
V1	V _{CCI}
V2	I/O
V3	I/O

329-Pin PBGA		
Pin Number	A54SX32 Function	
V4	I/O	
V20	I/O	
V21	I/O	
V22	I/O	
V23	I/O	
W1	I/O	
W2	I/O	
W3	I/O	
W4	I/O	
W20	I/O	
W21	I/O	
W22	I/O	

329-Pin PBGA	
Pin Number	A54SX32 Function
W23	NC
Y1	NC
Y2	I/O
Y3	1/0
Y4	GND
Y5	I/O
Y6	1/0
Y7	1/0
Y8	1/0
Y9	1/0
Y10	1/0
Y11	I/O

329-Pin PBGA	
Pin Number	A54SX32 Function
Y12	V_{CCA}
Y13	V_{CCR}
Y14	1/0
Y15	1/0
Y16	1/0
Y17	I/O
Y18	I/O
Y19	I/O
Y20	GND
Y21	I/O
Y22	I/O
Y23	I/O

2-22 v3.2